

SEMIPONT[®] 2

Controllable Bridge Rectifiers

SKCH 40

Features

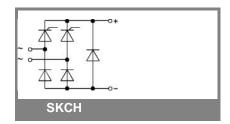
- Fully controlled single phase bridge rectifier
- Robust plastic case with screw terminals
- · Large, isolated base plate
- Blocking voltage to 1600V
- · High surge currents
- · Easy chassis mounting
- UL recognized, file no. E 63 532

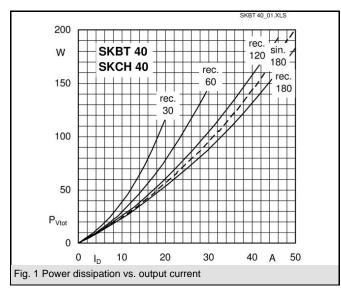
Typical Applications*

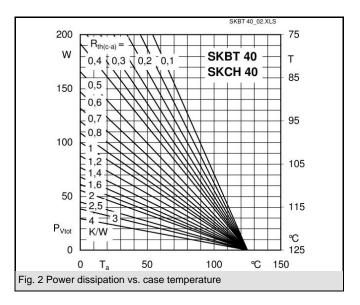
- For DC drives with a fixed direction of rotation
- Controlled field rectifiers for DC motors
- Controlled battery charger rectifiers
- 1) Painted metal shield of minimum 250 x 250 x 1 mm: $R_{th(c-a)}$ = 1,8 K/W

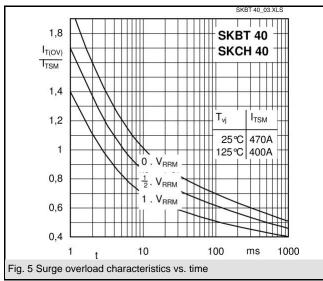
| V _{RSM} | V_{RRM}, V_{DRM} | I _D = 40 A (full conduction) |
|------------------|--------------------|---|
| V | V | (T _c = 92 °C) |
| 400 | 400 | SKCH 40/04 |
| 800 | 800 | SKCH 40/08 |
| 1200 | 1200 | SKCH 40/12 |
| 1400 | 1400 | SKCH 40/14 |
| 1600 | 1600 | SKCH 40/16 |

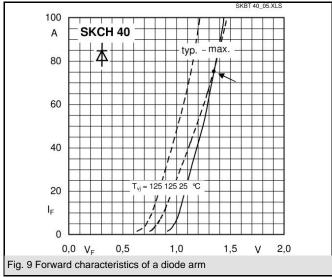
| Symbol | Conditions | Values | Units |
|-----------------------|---|-------------------|-------|
| I_D | T _c = 85 °C | 46 | А |
| | T _a = 45 °C; chassis ¹⁾ | 15 | Α |
| | T _a = 45 °C; R4A/120 | 18 | Α |
| | T _a = 45 °C; P13A/125 | 18 | Α |
| | T _a = 45 °C; P1A/120 | 28 | Α |
| I_{TSM}, I_{FSM} | T _{vj} = 25 °C; 10 ms | 470 | Α |
| | T _{vj} = 125 °C; 10 ms | 400 | Α |
| i²t | T _{vj} = 25 °C; 8,3 10 ms | 1100 | A²s |
| | T _{vj} = 125 °C; 8,3 10 ms | 800 | A²s |
| V_T | T _{vj} = 25 °C; I _T =75 A | max. 2,3 | V |
| $V_{T(TO)}$ | T _{vi} = 125 °C; | max. 1 | V |
| r _T | T _{vj} = 125 °C | max. 16 | mΩ |
| $I_{DD}; I_{RD}$ | T_{vj} = 125 °C; V_{DD} = V_{DRM} ; V_{RD} = V_{RRM} | max. 10 | mA |
| t _{gd} | $T_{vj} = 25 ^{\circ}\text{C}; I_{G} = 1 \text{A}; di_{G}/dt = 1 \text{A/}\mu\text{s}$ | 1 | μs |
| t_{gr} | $V_D = 0.67 \cdot V_{DRM}$ | 1 | μs |
| (dv/dt) _{cr} | T _{vi} = 125 °C | max. 500 | V/µs |
| (di/dt) _{cr} | $T_{vi} = 125 ^{\circ}\text{C}; f = 50 \text{Hz}$ | max. 50 | A/µs |
| t _q | $T_{vj} = 125 ^{\circ}\text{C}$; typ. | 80 | μs |
| I _H | T_{vj} = 25 °C; typ. / max. | 100 / 200 | mA |
| I_L | $T_{vj} = 25 ^{\circ}\text{C}; R_{G} = 33 \Omega$ | 250 / 400 | mA |
| V _{GT} | T _{vi} = 25 °C; d.c. | min. 3 | V |
| I_{GT} | $T_{vj}^{2} = 25 ^{\circ}\text{C}; \text{d.c.}$ | min. 150 | mA |
| V_{GD} | $T_{vj} = 125 ^{\circ}\text{C}; \text{d.c.}$ | max. 0,25 | V |
| I_{GD} | T _{vj} = 125 °C; d.c. | max. 5 | mA |
| R _{th(j-c)} | per thyristor / diode | 1 | K/W |
| • , | total | 0,25 | K/W |
| $R_{th(c-s)}$ | total | 0,05 | K/W |
| T_{vj} | | - 40 + 125 | °C |
| T _{stg} | | - 40 + 125 | °C |
| V _{isol} | a. c. 50 Hz; r.m.s.; 1 s / 1 min. | 3600 (3000) | V |
| M _s | to heatsink | 5 | Nm |
| M _t | to terminals | 3 | Nm |
| m | | 165 | g |
| Case | SKCH | G 19 | |

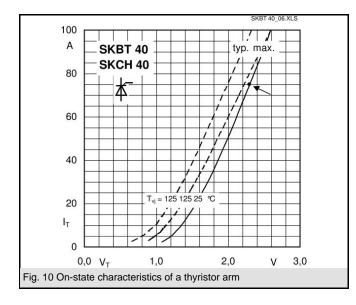


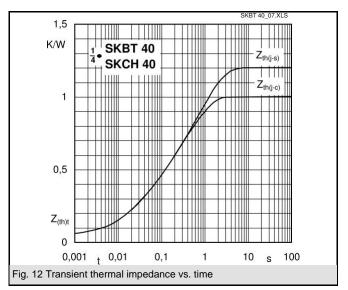


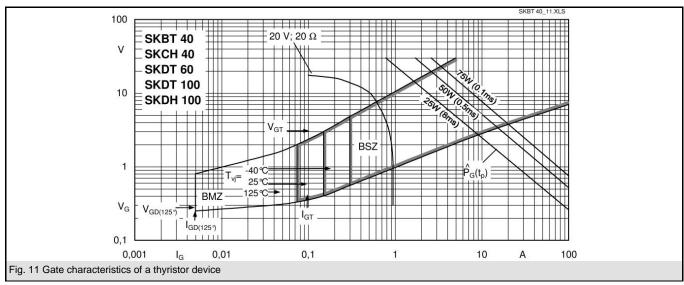


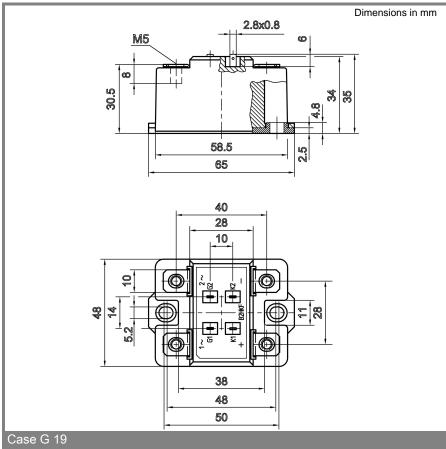












^{*} The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.